NSN 5962-01-058-9434

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View Online at https://aerobasegroup.com/nsn/5962-01-058-9434

Body Length:
Between 0.371 inches and 0.390 inches
Body Width:
Between 0.250 inches and 0.285 inches
Body Height:
Between 0.060 inches and 0.080 inches
Maximum Power Dissipation Rating:
550.0 milliwatts
Operating Tempurature Range:
-55.0/+110.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set, type an aps-125
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and w/decoded output and synchronous
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
13 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
20.00 nanoseconds propagation delay time, low to high level output and 20.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Precious Material And Location:
Terminals gold
Precious Material:
Gold
Test Data Document:
99971-7537102 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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